



#### 30V N-Channel Enhancement Mode MOSFET

Voltage 30 V Current 5.6A

#### **Features**

- RDS(ON), VGS@10V, ID@5.6A<30mΩ
- RDS(ON), VGS@4.5V, ID@3.5A<45mΩ</li>
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- Acquire quality system certificate: TS16949
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

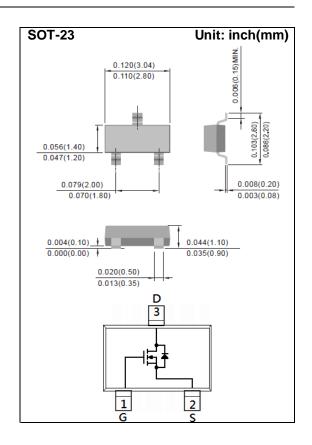
#### **Mechanical Data**

• Case: SOT-23 Package

Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A04



## Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	30	V
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V
Continuous Drain Current		I <sub>D</sub>	5.6	Α
Pulsed Drain Current		I <sub>DM</sub>	22	Α
Power Dissipation	T <sub>a</sub> =25°C	P <sub>D</sub>	1.25	W
	Derate above 25°C		10	mW/°C
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C
Typical Thermal Resistance				
- Junction to Ambient (Note 3)		$R_{\theta JA}$	100	°C/W





# **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	30	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=250uA$	1.0	1.33	2.1	V		
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =5.6A	-	27	30	mΩ		
		$V_{GS}$ =4.5V, $I_{D}$ =3.5A	-	39	45			
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =30V, $V_{GS}$ =0V	-	0.01	1	uA		
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = <u>+</u> 20V, V <sub>DS</sub> =0V	-	<u>+</u> 10	<u>+</u> 100	nA		
Dynamic								
Total Gate Charge	$Q_g$	V <sub>DS</sub> =15V, I <sub>D</sub> =5.6A, V <sub>GS</sub> =10V <sup>(Note 1,2)</sup>	-	7.8	-	nC		
Gate-Source Charge	$Q_gs$		-	1.2	-			
Gate-Drain Charge	$Q_{gd}$		-	1.5	-			
Input Capacitance	Ciss	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	343	-	pF		
Output Capacitance	Coss		-	48	-			
Reverse Transfer Capacitance	Crss		-	34	-			
Switching								
Turn-On Delay Time	td <sub>(on)</sub>	\/ 4E\/   E.CA	-	3	-			
Turn-On Rise Time	tr	$V_{DD}$ =15V, $I_{D}$ =5.6A, $V_{GS}$ =10V, $R_{G}$ =3 $\Omega$ (Note 1,2)	-	40	-	ns		
Turn-Off Delay Time	td <sub>(off)</sub>		-	38	-			
Turn-Off Fall Time	tf		-	39	-			
Drain-Source Diode								
Maximum Continuous Drain-Source		I <sub>S</sub>	-	-	1.5	А		
Diode Forward Current	IS							
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1.0A, V <sub>GS</sub> =0V	-	0.77	1.2	V		

#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





#### TYPICAL CHARACTERISTIC CURVES

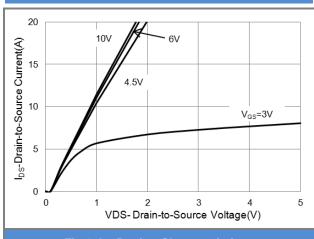
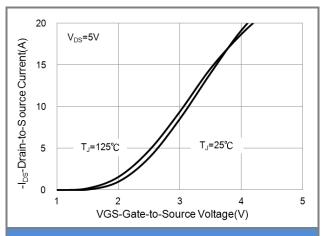


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

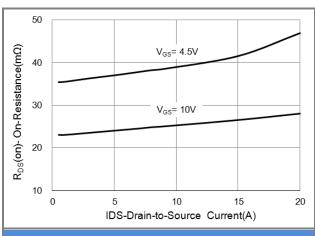


Fig.3 On-Resistance vs. Drain Current

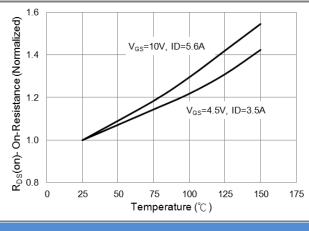


Fig.4 On-Resistance vs. Junction temperature

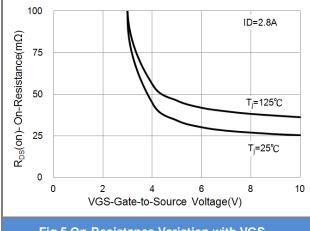
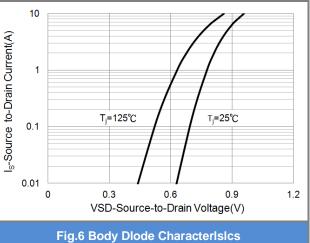


Fig.5 On-Resistance Variation with VGS.







#### **TYPICAL CHARACTERISTIC CURVES**

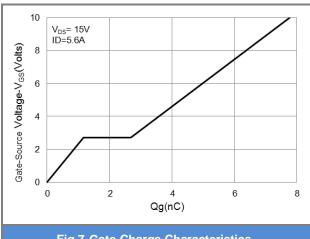


Fig.7 Gate-Charge Characteristics

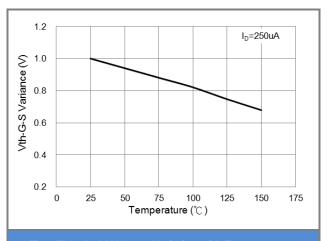


Fig.8 Threshold Voltage Variation with Temperature

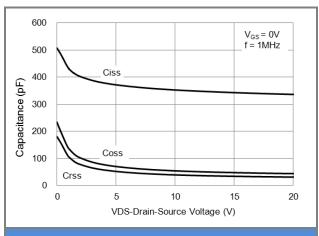


Fig.9 Capacitance vs. Drain-Source Voltage.

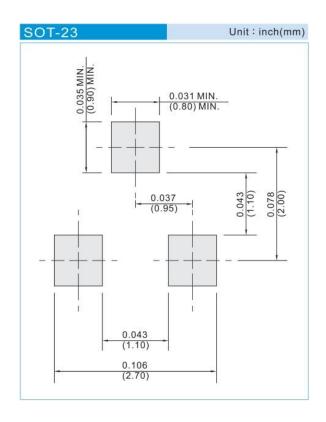




#### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJA3404-AU_R1_000A1	SOT-23	3K pcs / 7" reel	A04	Halogen free
PJA3404-AU_R2_000A1	SOT-23	12K pcs / 13" reel	A04	Halogen free

#### **MOUNTING PAD LAYOUT**







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EFC2J004NUZTDG FCAB21350L1 P85W28HP2F-7071 DMN1053UCP4-7 NTE2384 NTE2969 NTE6400A DMC2700UDMQ-7
DMN2080UCB4-7 DMN61D9UWQ-13 US6M2GTR DMN31D5UDJ-7 SSM6P54TU,LF DMP22D4UFO-7B IPS60R3K4CEAKMA1 DMN1006UCA6-7 DMN16M9UCA6-7 STF5N65M6 IRF40H233XTMA1 IPSA70R950CEAKMA1 IPSA70R2K0CEAKMA1 STU5N65M6 C3M0021120D